Amendments to the Claims:

This listing of claims will replace all prior versions, and listings of claims in the application:

Listing of Claims:

1. (Currently Amended) A light source comprising:

a. a light emitting component comprised of a semiconductor material,

b. at least one phosphor material, and

c. at least one UV reflecting material,

wherein said UV reflecting material reflects at least a substantial portion of UV light emitted by said light emitting component and allows at least a substantial portion of visible light to pass through.

2. (Original) The light source of claim 1 wherein the light emitting component comprises a light emitting diode or a laser diode.

3. (Original) The light source of claim 2 wherein the light emitting component emits light in at least one of the blue region and the UV region of the electromagnetic spectrum.

4. (Original) The light source of claim 1, wherein said phosphor is excited by light emitted from the said light emitting component.

5. (Previously presented) The light source of claim 1 wherein said phosphor material converts UV light to visible.

6. (Previously presented) The light source of claim 1 wherein said UV reflecting material reflects UV light into the phosphor material.

7. (Previously cancelled)

8. (Previously presented) The light source of claim 1 wherein said UV reflecting material reflects at least 90% of any UV light not converted to visible light by said phosphor material.

9. (Original) The light source of claim 1 wherein said UV reflecting material comprises alumina.

10. (Previously presented) The light source of claim 1 wherein said UV reflecting material comprises alpha alumina, gamma alumina, and mixtures thereof.

11. (Previously presented) The light source of claim 10 wherein said UV reflecting material comprises about 5-80 wt% gamma alumina and about 20-95 wt% alpha alumina.

12. (Currently Amended) The light source of claim 1 wherein said UV reflecting material is disposed as a layer adjacent to the phosphor material, said layer positioned outwardly from said phosphor material in a direction of light emission from said light source.

13. (Currently Amended) The light source of claim 1 wherein said UV reflecting material is disposed as a layer adjacent a layer of a transparent epoxy material and closer to said light emitting component relative to said transparent epoxy material.

14. (Previously presented) The light source of claim 1 wherein said UV reflecting material is dispersed in a phosphor material containing layer.

15. (Previously presented) The light source of claim 14 wherein the concentration of UV reflecting material dispersed throughout the phosphor material containing layer is not greater than about 25% by volume of said phosphor material.

16. (Previously presented) The light source of claim 1 wherein said UV reflecting material reflects light in the range of about 350-400 nm.

17. (Previously presented) The light source of claim 1 wherein said phosphor material converts light reflected by the UV reflecting material to visible light.

18. (Currently amended) A white light emitting device comprising:

a. a light emitting diode,

b. at least one phosphor containing layer,

c. at least one UV reflecting material containing layer, and

d. at least one encapsulant layer, said UV reflecting material containing layer disposed outwardly from said phosphor containing layer, and wherein a substantial portion of visible light is allowed to pass through the UV reflecting material containing layer.

19. (Currently amended) A light emitting device comprising:

a. an LED of the formula $In_IGa_JAl_KN$, wherein I, J, and K are each greater than or equal to zero, and I+J+K=1,

b. a phosphor layer, and

c. an encapsulant layer including a UV reflecting material and/or a UV reflecting layer, and wherein said encapsulant layer allows at least a substantial portion of visible light to pass through.

20. (New) The light source of claim 1 wherein said UV reflecting material allows at least 90% of visible light to pass.

21. (New) The white light emitting device of claim 18 wherein said UV reflecting material containing layer allows at least 90% of visible light to pass through.

22. (New) The light emitting device of claim 19 wherein said encapsulant layer allows at least 90% of visible light to pass through.